



PNP Silicon Epitaxial Planar Transistor

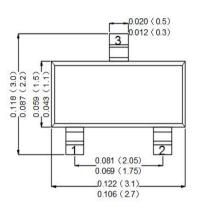
SOT-23

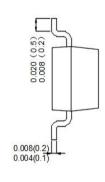
Features

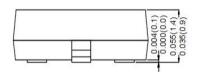
- For general purpose application
- This device is designed for low level, high gain, low noise general purpose amplifier applications at collector currents to 50mA

Mechanical Data

- Case:Molded Plastic,SOT-23
- Epoxy:UL 94V-0 rate flame retardant
- Terminals:Plated Leads Solderable perMIL-STD-750,Method-2026.
- Marking: 2Q
- Mounting Position : Any.
- Equivalent Circuit:







Dimensions in inches and (millimeters)

Maximum Ratings Maximum Ratings (Rating at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Collector Base Voltage	-V _{CBO}	50	V
Collector Emitter Voltage	-V _{CEO}	50	V
Emitter Base Voltage	-V _{EBO}	3	V
Collector Current	-I _C	100	mA
Peak Collector Current	-I _{CM}	200	mA
Power Dissipation	P _{tot}	350	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	Ts	- 55 to + 150	°C

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Electrical Characteristics (Rating at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain				
at $-V_{CE} = 5 \text{ V}$, $-I_{C} = 100 \mu\text{A}$	h _{FE}	250	800	-
at $-V_{CE} = 5 \text{ V}, -I_{C} = 1 \text{ mA}$	h _{FE}	250	-	-
at $-V_{CE} = 5 \text{ V}$, $-I_{C} = 10 \text{ mA}$	h _{FE}	250	-	-
Collector Cutoff Current			50	A
at -V _{CB} = 35 V	-I _{CBO}	-	50	nA
Emitter Cutoff Current			50	- 0
at $-V_{EB} = 3 \text{ V}$	-I _{EBO}	-	50	nA
Collector Base Breakdown Voltage		F0		
at $-I_C = 100 \mu A$	-V _{(BR)CBO}	50	-	V
Collector Emitter Breakdown Voltage		F0		
at $-I_C = 1 \text{ mA}$	-V _{(BR)CEO}	50	-	V
Emitter Base Breakdown Voltage		3		\ /
at -I _E = 100 μA	-V _{(BR)EBO}	3	-	V
Collector Emitter Saturation Voltage	\/		0.0	
at $-I_C = 10 \text{ mA}, -I_B = 1 \text{ mA}$	-V _{CE(sat)}	-	0.3	V
Base Emitter On Voltage	1/		0.05	
at $-V_{CE} = 5 \text{ V}$, $-I_{C} = 1 \text{ mA}$	-V _{BE(on)}	-	0.85	V
Transition Frequency		40		N 41 1
at $-V_{CE} = 5 \text{ V}$, $I_E = 0.5 \text{ mA}$, $f = 100 \text{ MHz}$	f⊤	40	-	MHz
Collector Base Capacitance	6		4	
at $-V_{CE} = 5 \text{ V}$, $I_{E} = 0$, $f = 100 \text{ KHz}$	C_cb	-	4	pF

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Rating And Characteristic Curves

50 L 0.01

0.03

0.1

0.3

I_c - COLLECTOR CURRENT (mA)

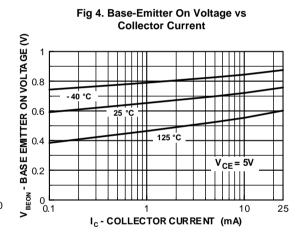
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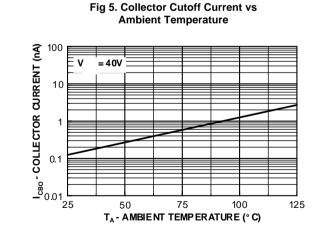
Fig 1. Typical Pulsed Current Gain vs **Collector Current**

Collector Current 125 °C 0.1 Ic - COLLECTOR CURRENT (mA)

Fig 2. Collector-Emitter Saturation Voltage vs

Fig 3. Base-Emitter Saturation Voltage vs **Collector Current** V_{BESAT}- BASE EMITTER VOLTAGE (V) 125 °C $\beta = 10$ 0.1 50 10 I C - COLLECTOR CURRENT (mA)





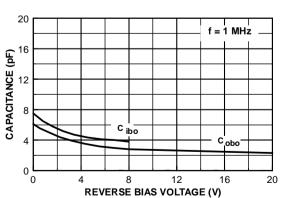


Fig 6. Input and Output Capacitance vs

Reverse Voltag

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